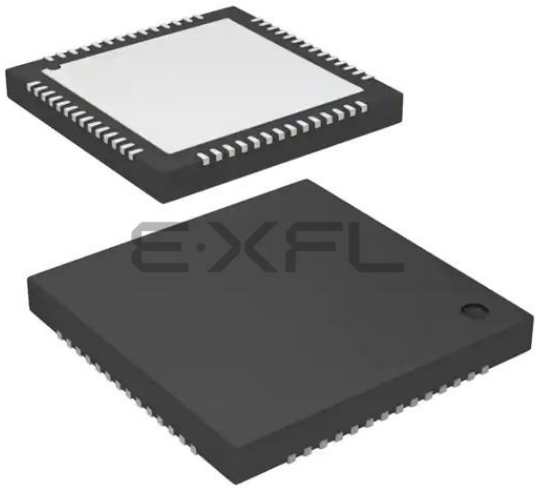

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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	M8C
Core Size	8-Bit
Speed	24MHz
Connectivity	I²C, SPI, UART/USART, USB
Peripherals	POR, PWM, WDT
Number of I/O	50
Program Memory Size	16KB (16K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	1K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.25V
Data Converters	A/D 48x14b; D/A 2x9b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	56-VFQFN Exposed Pad
Supplier Device Package	56-QFN (8x8)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/cy8c24794-24ltxi

5. PSoC Functional Overview

The PSoC family consists of many devices with on-chip controllers. These devices are designed to replace multiple traditional MCU-based system components with one low-cost single-chip programmable component. A PSoC device includes configurable blocks of analog and digital logic, and programmable interconnect. This architecture makes it possible for you to create customized peripheral configurations, to match the requirements of each individual application. Additionally, a fast central processing unit (CPU), flash program memory, SRAM data memory, and configurable I/O are included in a range of convenient pinouts.

The PSoC architecture, shown in "Logic Block Diagram" on page 1, consists of four main areas: the core, the system resources, the digital system, and the analog system. Configurable global bus resources allow combining all of the device resources into a complete custom system. Each CY8C24x94 PSoC device includes four digital blocks and six analog blocks. Depending on the PSoC package, up to 56 GPIOs are also included. The GPIOs provide access to the global digital and analog interconnects.

5.1 The PSoC Core

The PSoC core is a powerful engine that supports a rich instruction set. It encompasses SRAM for data storage, an interrupt controller, sleep and watchdog timers, and internal main oscillator (IMO) and internal low-speed oscillator (ILO). The CPU core, called the M8C, is a powerful processor with speeds up to 24 MHz. The M8C is a four-million instructions per second (MIPS) 8-bit Harvard-architecture microprocessor.

System resources provide these additional capabilities:

- Digital clocks for increased flexibility
- I^2C functionality to implement an I^2C master and slave
- An internal voltage reference, multi-master, that provides an absolute value of 1.3 V to a number of PSoC subsystems
- A switch-mode pump (SMP) that generates normal operating voltages from a single battery cell
- Various system resets supported by the M8C

The digital system consists of an array of digital PSoC blocks that may be configured into any number of digital peripherals. The digital blocks are connected to the GPIOs through a series of global buses. These buses can route any signal to any pin, freeing designs from the constraints of a fixed peripheral controller.

The analog system consists of six analog PSoC blocks, supporting comparators, and analog-to-digital conversion up to 10-bits of precision.

5.2 The Digital System

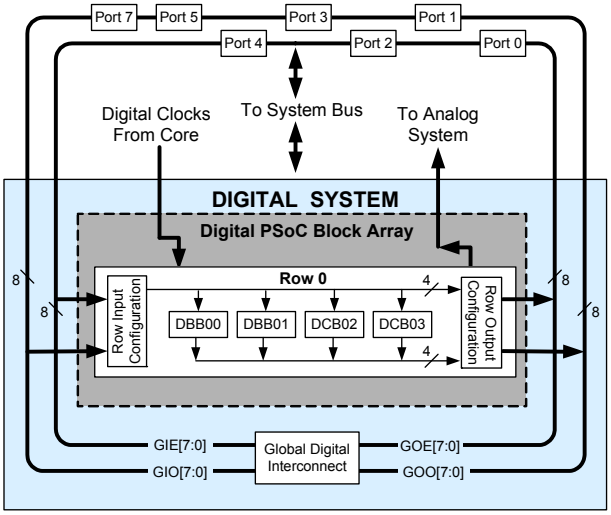
The digital system consists of four digital PSoC blocks. Each block is an 8-bit resource that is used alone or combined with other blocks to form 8-, 16-, 24-, and 32-bit peripherals, which are called user modules. Digital peripheral configurations include:

- PWMs (8- to 32-bit)
- PWMs with dead band (8- to 32-bit)
- Counters (8- to 32-bit)
- Timers (8- to 32-bit)
- UART 8-bit with selectable parity
- SPI master and slave
- I^2C slave and multi-master
- CRC/generator (8-bit)
- IrDA
- PRS generators (8- to 32-bit)

The digital blocks are connected to any GPIO through a series of global buses that can route any signal to any pin. The buses also allow for signal multiplexing and for performing logic operations. This configurability frees your designs from the constraints of a fixed peripheral controller.

Digital blocks are provided in rows of four, where the number of blocks varies by PSoC device family. This allows the optimum choice of system resources for your application. Family resources are shown in Table 1 on page 7.

Figure 2. Digital System Block Diagram

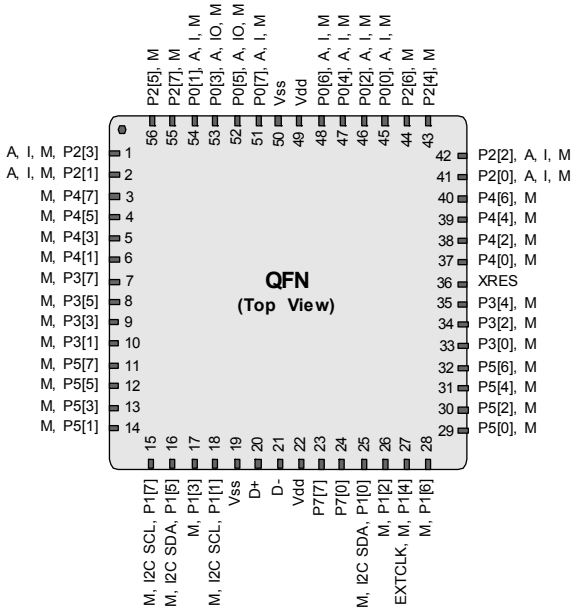


9.2 56-Pin Part Pinout (with XRES)

Table 3. 56-Pin Part Pinout (QFN[6])

Pin No.	Type		Name	Description
	Digital	Analog		
1	I/O	I, M	P2[3]	Direct switched capacitor block input
2	I/O	I, M	P2[1]	Direct switched capacitor block input
3	I/O	M	P4[7]	
4	I/O	M	P4[5]	
5	I/O	M	P4[3]	
6	I/O	M	P4[1]	
7	I/O	M	P3[7]	
8	I/O	M	P3[5]	
9	I/O	M	P3[3]	
10	I/O	M	P3[1]	
11	I/O	M	P5[7]	
12	I/O	M	P5[5]	
13	I/O	M	P5[3]	
14	I/O	M	P5[1]	
15	I/O	M	P1[7]	I^2C SCL
16	I/O	M	P1[5]	I^2C SDA
17	I/O	M	P1[3]	
18	I/O	M	P1[1]	I^2C SCL, ISSP SCLK [7]
19	Power		V_{SS}	Ground connection [8]
20	USB		D+	
21	USB		D–	
22	Power		V_{DD}	Supply voltage
23	I/O		P7[7]	
24	I/O		P7[0]	
25	I/O	M	P1[0]	I^2C SDA, ISSP SDATA[7]
26	I/O	M	P1[2]	
27	I/O	M	P1[4]	Optional EXTCLK
28	I/O	M	P1[6]	
29	I/O	M	P5[0]	
30	I/O	M	P5[2]	
31	I/O	M	P5[4]	
32	I/O	M	P5[6]	
33	I/O	M	P3[0]	
34	I/O	M	P3[2]	
35	I/O	M	P3[4]	
36	Input		XRES	Active high external reset with internal pull-down
37	I/O	M	P4[0]	
38	I/O	M	P4[2]	
39	I/O	M	P4[4]	
40	I/O	M	P4[6]	
41	I/O	I, M	P2[0]	Direct switched capacitor block input
42	I/O	I, M	P2[2]	Direct switched capacitor block input
43	I/O	M	P2[4]	External AGND input
44	I/O	M	P2[6]	External VREF input
45	I/O	I, M	P0[0]	Analog column mux input
46	I/O	I, M	P0[2]	Analog column mux input
47	I/O	I, M	P0[4]	Analog column mux input VREF
48	I/O	I, M	P0[6]	Analog column mux input
49	Power		V_{DD}	Supply voltage
50	Power		V_{SS}	Ground connection [8]
51	I/O	I, M	P0[7]	Analog column mux input
52	I/O	I/O, M	P0[5]	Analog column mux input and column output
53	I/O	I/O, M	P0[3]	Analog column mux input and column output
54	I/O	I, M	P0[1]	Analog column mux input
55	I/O	M	P2[7]	
56	I/O	M	P2[5]	

Figure 5. CY8C24894 56-Pin PSoC Device



LEGEND A = Analog, I = Input, O = Output, and M = Analog Mux Input.

Notes
6. The center pad on the QFN package should be connected to ground (V_{SS}) for best mechanical, thermal, and electrical performance. If not connected to ground, it should be electrically floated and not connected to any other signal.
7. These are the ISSP pins, which are not High Z at POR. See the PSoC Technical Reference Manual for details.
8. All V_{SS} pins should be brought out to one common GND plane.

9.4 68-Pin Part Pinout (On-Chip Debug)

The following 68-pin QFN part table and drawing is for the CY8C24094 OCD PSoC device.

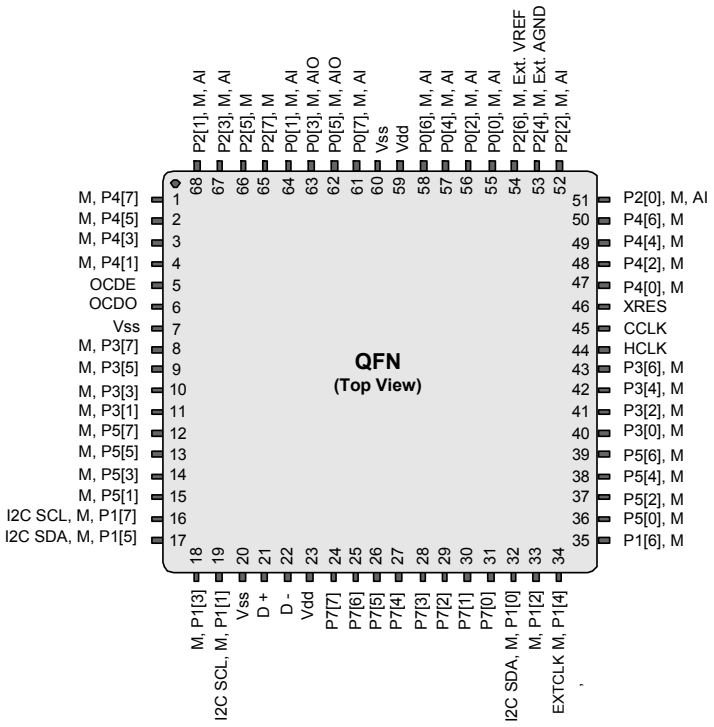
Note This part is only used for in-circuit debugging. It is NOT available for production.

Table 5. 68-Pin Part Pinout (QFN[12])

Pin No.	Type		Name	Description
	Digital	Analog		
1	I/O	M	P4[7]	
2	I/O	M	P4[5]	
3	I/O	M	P4[3]	
4	I/O	M	P4[1]	
5			OCDE	OCD even data I/O
6			OCDO	OCD odd data output
7	Power		V_{SS}	Ground connection [13]
8	I/O	M	P3[7]	
9	I/O	M	P3[5]	
10	I/O	M	P3[3]	
11	I/O	M	P3[1]	
12	I/O	M	P5[7]	
13	I/O	M	P5[5]	
14	I/O	M	P5[3]	
15	I/O	M	P5[1]	
16	I/O	M	P1[7]	I^2C SCL
17	I/O	M	P1[5]	I^2C SDA
18	I/O	M	P1[3]	
19	I/O	M	P1[1]	I^2C SCL, ISSP SCLK [14]
20	Power		V_{SS}	Ground connection [13]
21	USB		D+	
22	USB		D–	
23	Power		V_{DD}	Supply voltage
24	I/O		P7[7]	
25	I/O		P7[6]	
26	I/O		P7[5]	
27	I/O		P7[4]	
28	I/O		P7[3]	
29	I/O		P7[2]	
30	I/O		P7[1]	
31	I/O		P7[0]	
32	I/O	M	P1[0]	I^2C SDA, ISSP SDATA[14]
33	I/O	M	P1[2]	
34	I/O	M	P1[4]	Optional EXTCLK
35	I/O	M	P1[6]	
36	I/O	M	P5[0]	
37	I/O	M	P5[2]	
38	I/O	M	P5[4]	
39	I/O	M	P5[6]	
40	I/O	M	P3[0]	
41	I/O	M	P3[2]	
42	I/O	M	P3[4]	
43	I/O	M	P3[6]	
44			HCLK	OCD high speed clock output
45			CCLK	OCD CPU clock output
46	Input		XRES	Active high pin reset with internal pull-down
47	I/O	M	P4[0]	
48	I/O	M	P4[2]	
49	I/O	M	P4[4]	
50	I/O	M	P4[6]	
51	I/O	I, M	P2[0]	Direct switched capacitor block input
52	I/O	I, M	P2[2]	Direct switched capacitor block input
53	I/O	M	P2[4]	External AGND input
54	I/O	M	P2[6]	External VREF input
55	I/O	I, M	P0[0]	Analog column mux input
56	I/O	I, M	P0[2]	Analog column mux input and column output
57	I/O	I, M	P0[4]	Analog column mux input and column output
58	I/O	I, M	P0[6]	Analog column mux input
59	Power		V_{DD}	Supply voltage
60	Power		V_{SS}	Ground connection [13]
61	I/O	I, M	P0[7]	Analog column mux input, integration input #1
62	I/O	I/O, M	P0[5]	Analog column mux input and column output, integration input #2
63	I/O	I/O, M	P0[3]	Analog column mux input and column output
64	I/O	I, M	P0[1]	Analog column mux input
65	I/O	M	P2[7]	
66	I/O	M	P2[5]	
67	I/O	I, M	P2[3]	Direct switched capacitor block input
68	I/O	I, M	P2[1]	Direct switched capacitor block input

LEGEND A = Analog, I = Input, O = Output, M = Analog Mux Input, OCD = On-Chip Debugger.

Figure 7. CY8C24094 68-Pin OCD PSoC Device



Notes

12. The center pad on the QFN package should be connected to ground (V_{SS}) for best mechanical, thermal, and electrical performance. If not connected to ground, it should be electrically floated and not connected to any other signal.
13. All V_{SS} pins should be brought out to one common GND plane.
14. These are the ISSP pins, which are not High Z at POR. See the PSoC Technical Reference Manual for details.

9.6 100-Ball VFBGA Part Pinout (On-Chip Debug)

The following 100-pin VFBGA part table and drawing is for the CY8C24094 OCD PSoC device.

Note This part is only used for in-circuit debugging. It is NOT available for production.

Table 7. 100-Ball Part Pinout (VFBGA[17])

Pin No.	Digital	Analog	Name	Description	Pin No.	Digital	Analog	Name	Description
A1	Power		V_{SS}	Ground connection	F1			OCDE	OCD even data I/O
A2	Power		V_{SS}	Ground connection	F2	I/O	M	P5[7]	
A3			NC	No connection. Pin must be left floating	F3	I/O	M	P3[5]	
A4			NC	No connection. Pin must be left floating	F4	I/O	M	P5[1]	
A5			NC	No connection. Pin must be left floating.	F5	Power		V_{SS}	Ground connection
A6	Power		V_{DD}	Supply voltage.	F6	Power		V_{SS}	Ground connection
A7			NC	No connection. Pin must be left floating.	F7	I/O	M	P5[0]	
A8			NC	No connection. Pin must be left floating.	F8	I/O	M	P3[0]	
A9	Power		V_{SS}	Ground connection	F9			XRES	Active high pin reset with internal pull-down
A10	Power		V_{SS}	Ground connection	F10	I/O		P7[1]	
B1	Power		V_{SS}	Ground connection	G1			OCDO	OCD odd data output
B2	Power		V_{SS}	Ground connection	G2	I/O	M	P5[5]	
B3	I/O	I, M	P2[1]	Direct switched capacitor block input	G3	I/O	M	P3[3]	
B4	I/O	I, M	P0[1]	Analog column mux input	G4	I/O	M	P1[7]	I^2C SCL
B5	I/O	I, M	P0[7]	Analog column mux input	G5	I/O	M	P1[1]	I^2C SCL, ISSP SCLK[18]
B6	Power		V_{DD}	Supply voltage	G6	I/O	M	P1[0]	I^2C SDA, ISSP SDATA[18]
B7	I/O	I, M	P0[2]	Analog column mux input	G7	I/O	M	P1[6]	
B8	I/O	I, M	P2[2]	Direct switched capacitor block input	G8	I/O	M	P3[4]	
B9	Power		V_{SS}	Ground connection	G9	I/O	M	P5[6]	
B10	Power		V_{SS}	Ground connection	G10	I/O		P7[2]	
C1			NC	No connection. Pin must be left floating	H1			NC	No connection. Pin must be left floating
C2	I/O	M	P4[1]		H2	I/O	M	P5[3]	
C3	I/O	M	P4[7]		H3	I/O	M	P3[1]	
C4	I/O	M	P2[7]		H4	I/O	M	P1[5]	I^2C SDA
C5	I/O	I/O,M	P0[5]	Analog column mux input and column output	H5	I/O	M	P1[3]	
C6	I/O	I, M	P0[6]	Analog column mux input	H6	I/O	M	P1[2]	
C7	I/O	I, M	P0[0]	Analog column mux input	H7	I/O	M	P1[4]	Optional EXTCLK
C8	I/O	I, M	P2[0]	Direct switched capacitor block input	H8	I/O	M	P3[2]	
C9	I/O	M	P4[2]		H9	I/O	M	P5[4]	
C10			NC	No connection. Pin must be left floating	H10	I/O		P7[3]	
D1			NC	No connection. Pin must be left floating	J1	Power		V_{SS}	Ground connection
D2	I/O	M	P3[7]		J2	Power		V_{SS}	Ground connection
D3	I/O	M	P4[5]		J3	USB		D+	
D4	I/O	M	P2[5]		J4	USB		D-	
D5	I/O	I/O, M	P0[3]	Analog column mux input and column output	J5	Power		V_{DD}	Supply voltage
D6	I/O	I, M	P0[4]	Analog column mux input	J6	I/O		P7[7]	
D7	I/O	M	P2[6]	External VREF input	J7	I/O		P7[0]	
D8	I/O	M	P4[6]		J8	I/O	M	P5[2]	
D9	I/O	M	P4[0]		J9	Power		V_{SS}	Ground connection
D10			CCLK	OCD CPU clock output	J10	Power		V_{SS}	Ground connection
E1			NC	No connection. Pin must be left floating	K1	Power		V_{SS}	Ground connection
E2			NC	No connection. Pin must be left floating	K2	Power		V_{SS}	Ground connection
E3	I/O	M	P4[3]		K3			NC	No connection. Pin must be left floating
E4	I/O	I, M	P2[3]	Direct switched capacitor block input	K4			NC	No connection. Pin must be left floating
E5	Power		V_{SS}	Ground connection	K5	Power		V_{DD}	Supply voltage
E6	Power		V_{SS}	Ground connection	K6	I/O		P7[6]	
E7	I/O	M	P2[4]	External AGND input	K7	I/O		P7[5]	
E8	I/O	M	P4[4]		K8	I/O		P7[4]	
E9	I/O	M	P3[6]		K9	Power		V_{SS}	Ground connection
E10			HCLK	OCD high speed clock output	K10	Power		V_{SS}	Ground connection

LEGEND A = Analog, I = Input, O = Output, M = Analog Mux Input, NC = No connection. Pin must be left floating, OCD = On-Chip Debugger.

Notes

17. All V_{SS} pins should be brought out to one common GND plane.
18. These are the ISSP pins, which are not High Z at POR. See the PSoC Technical Reference Manual for details.

10. Register Reference

This section lists the registers of the CY8C24x94 PSoC device family. For detailed register information, see the *PSoC Technical Reference Manual*.

10.1 Register Conventions

The register conventions specific to this section are listed in the following table.

Convention	Description
R	Read register or bit(s)
W	Write register or bit(s)
L	Logical register or bit(s)
C	Clearable register or bit(s)
#	Access is bit specific

10.2 Register Mapping Tables

The PSoC device has a total register address space of 512 bytes. The register space is referred to as I/O space and is divided into two banks, Bank 0 and Bank 1. The XOI bit in the Flag register (CPU_F) determines which bank the user is currently in. When the XOI bit is set to 1, the user is in Bank 1.

Note In the following register mapping tables, blank fields are Reserved and should not be accessed.

11.2 Operating Temperature

Table 10. Operating Temperature

Symbol	Description	Min	Typ	Max	Units	Notes
T_A	Ambient temperature	–40	–	+85	°C	
T_{AUSB}	Ambient temperature using USB	–10	–	+85	°C	
T_J	Junction temperature	–40	–	+100	°C	The temperature rise from ambient to junction is package specific. See Thermal Impedance on page 51. The user must limit the power consumption to comply with this requirement.

11.3 DC Electrical Characteristics

11.3.1 DC Chip-Level Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters are measured at 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 11. DC Chip-Level Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
V_{DD}	Supply voltage	3.0	–	5.25	V	See DC POR and LVD specifications, Table 22 on page 39.
I_{DD5}	Supply current, IMO = 24 MHz (5 V)	–	14	27	mA	Conditions are V_{DD} = 5.0 V, T_A = 25 °C, CPU = 3 MHz, SYSCLK doubler disabled, VC1 = 1.5 MHz, VC2 = 93.75 kHz, VC3 = 93.75 kHz, analog power = off.
I_{DD3}	Supply current, IMO = 24 MHz (3.3 V)	–	8	14	mA	Conditions are V_{DD} = 3.3 V, T_A = 25 °C, CPU = 3 MHz, SYSCLK doubler disabled, VC1 = 1.5 MHz, VC2 = 93.75 kHz, VC3 = 0.367 kHz, analog power = off.
I_{SB}	Sleep [21] (mode) current with POR, LVD, sleep timer, and WDT.[22]	–	3	6.5	µA	Conditions are with internal slow speed oscillator, V_{DD} = 3.3 V, –40 °C ≤ T_A ≤ 55 °C, analog power = off.
I_{SBH}	Sleep (mode) current with POR, LVD, Sleep Timer, and WDT at high temperature.[22]	–	4	25	µA	Conditions are with internal slow speed oscillator, V_{DD} = 3.3 V, 55 °C < T_A ≤ 85 °C, analog power = off.

Notes
21. Errata: When the device is operating at 4.75 V to 5.25 V and the 3.3 V regulator is enabled, a short low pulse may be created on the DP signal line during device wake-up. The 15-20 µs low pulse of the DP line may be interpreted by the host computer as a deattach or the beginning of a wake-up. More details in "Errata" on page 66.
22. Standby current includes all functions (POR, LVD, WDT, Sleep Time) needed for reliable system operation. This should be compared with devices that have similar functions enabled.

11.3.3 DC Full Speed USB Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –10 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –10 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters are measured at 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 13. DC Full Speed (12 Mbps) USB Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
USB Interface						
V_{DI}	Differential input sensitivity	0.2	–	–	V	| (D+) – (D–) |
V_{CM}	Differential input common mode range	0.8	–	2.5	V	
V_{SE}	Single ended receiver threshold	0.8	–	2.0	V	
C_{IN}	Transceiver capacitance	–	–	20	pF	
$I_{I/O}$	High Z state data line leakage	–10	–	10	µA	0 V < V_{IN} < 3.3 V.
R_{EXT}	External USB series resistor	23	–	25	Ω	In series with each USB pin.
V_{UOH}	Static output high, driven	2.8	–	3.6	V	15 kΩ ± 5% to ground. Internal pull-up enabled.
V_{UOHI}	Static output high, idle	2.7	–	3.6	V	15 kΩ ± 5% to ground. Internal pull-up enabled.
V_{UOL}	Static output low	–	–	0.3	V	15 kΩ ± 5% to ground. Internal pull-up enabled.
Z_O	USB driver output impedance	28	–	44	Ω	Including R_{EXT} resistor.
V_{CRS}	D+/D– crossover voltage	1.3	–	2.0	V	

Table 15. 3.3-V DC Operational Amplifier Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
V_{OSOA}	Input offset voltage (absolute value) Power = low, Opamp bias = high Power = medium, Opamp bias = high Power = high, Opamp bias = high	 – – –	 1.65 1.32 –	 10 8 –	 mV mV mV	Power = high, Opamp bias = high setting is not allowed for 3.3 V V_{DD} operation
TCV_{OSOA}	Average input offset voltage drift	–	7.0	35.0	µV/°C	
I_{EBOA}	Input leakage current (port 0 analog pins)	–	20	–	pA	Gross tested to 1 µA.
C_{INOA}	Input capacitance (port 0 analog pins)	–	4.5	9.5	pF	Package and pin dependent. Temp = 25 °C.
V_{CMOA}	Common mode voltage range	0.2	–	V_{DD} – 0.2	V	The common-mode input voltage range is measured through an analog output buffer. The specification includes the limitations imposed by the characteristics of the analog output buffer.
G_{OLOA}	Open loop gain Power = low, Opamp bias = low Power = medium, Opamp bias = low Power = high, Opamp bias = low	 60 60 80	 – – –	 – – –	 dB dB dB	Specification is applicable at Low opamp bias. For high opamp bias mode (except high power, High opamp bias), minimum is 60 dB.
$V_{OHIGHOA}$	High output voltage swing (internal signals) Power = low, Opamp bias = low Power = medium, Opamp bias = low Power = high, Opamp bias = low	 V_{DD} – 0.2 V_{DD} – 0.2 V_{DD} – 0.2	 – – –	 – – –	 V V V	Power = high, Opamp bias = high setting is not allowed for 3.3 V V_{DD} operation
V_{OLOWOA}	Low output voltage swing (internal signals) Power = low, Opamp bias = low Power = medium, Opamp bias = low Power = high, Opamp bias = low	 – – –	 – – –	 0.2 0.2 0.2	 V V V	Power = high, Opamp bias = high setting is not allowed for 3.3 V V_{DD} operation
I_{SOA}	Supply current (including associated AGND buffer) Power = low, Opamp bias = low Power = low, Opamp bias = high Power = medium, Opamp bias = low Power = medium, Opamp bias = high Power = high, Opamp bias = low Power = high, Opamp bias = high	 – – – – – –	 400 500 800 1200 2400 –	 800 900 1000 1600 3200 –	 µA µA µA µA µA µA	Power = high, Opamp bias = high setting is not allowed for 3.3 V V_{DD} operation
$PSRR_{OA}$	Supply voltage rejection ratio	65	80	–	dB	$V_{SS} \le V_{IN} \le (V_{DD} – 2.25)$ or $(V_{DD} – 1.25\ V) \le V_{IN} \le V_{DD}$

11.3.5 DC Low Power Comparator Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters are measured at 5 V at 25 °C and are for design guidance only.

Table 16. DC Low Power Comparator Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
V_{REFLPC}	Low power comparator (LPC) reference voltage range	0.2	–	V_{DD} – 1	V	
I_{SLPC}	LPC supply current	–	10	40	µA	
V_{OSLPC}	LPC voltage offset	–	2.5	30	mV	

11.3.7 DC Analog Reference Specifications

The following tables list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

The guaranteed specifications for RefHI and RefLo are measured through the Analog Continuous Time PSoC blocks. The power levels for RefHi and RefLo refer to the Analog Reference Control register. AGND is measured at P2[4] in AGND bypass mode. Each Analog Continuous Time PSoC block adds a maximum of 10mV additional offset error to guaranteed AGND specifications from the local AGND buffer. Reference control power can be set to medium or high unless otherwise noted.

Note Avoid using P2[4] for digital signaling when using an analog resource that depends on the Analog Reference. Some coupling of the digital signal may appear on the AGND.

Table 19. 5-V DC Analog Reference Specifications

Reference ARF_CR [5:3]	Reference Power Settings	Symbol	Reference	Description	Min	Typ	Max	Units
0b000	RefPower = high Opamp bias = high	V_{REFHI}	Ref High	$V_{DD}/2$ + Bandgap	$V_{DD}/2$ + 1.229	$V_{DD}/2$ + 1.290	$V_{DD}/2$ + 1.346	V
		V_{AGND}	AGND	$V_{DD}/2$	$V_{DD}/2$ – 0.038	$V_{DD}/2$	$V_{DD}/2$ + 0.040	V
		V_{REFLO}	Ref Low	$V_{DD}/2$ – Bandgap	$V_{DD}/2$ – 1.356	$V_{DD}/2$ – 1.295	$V_{DD}/2$ – 1.218	V
	RefPower = high Opamp bias = low	V_{REFHI}	Ref High	$V_{DD}/2$ + Bandgap	$V_{DD}/2$ + 1.220	$V_{DD}/2$ + 1.292	$V_{DD}/2$ + 1.348	V
		V_{AGND}	AGND	$V_{DD}/2$	$V_{DD}/2$ – 0.036	$V_{DD}/2$	$V_{DD}/2$ + 0.036	V
		V_{REFLO}	Ref Low	$V_{DD}/2$ – Bandgap	$V_{DD}/2$ – 1.357	$V_{DD}/2$ – 1.297	$V_{DD}/2$ – 1.225	V
	RefPower = medium Opamp bias = high	V_{REFHI}	Ref High	$V_{DD}/2$ + Bandgap	$V_{DD}/2$ + 1.221	$V_{DD}/2$ + 1.293	$V_{DD}/2$ + 1.351	V
		V_{AGND}	AGND	$V_{DD}/2$	$V_{DD}/2$ – 0.036	$V_{DD}/2$	$V_{DD}/2$ + 0.036	V
		V_{REFLO}	Ref Low	$V_{DD}/2$ – Bandgap	$V_{DD}/2$ – 1.357	$V_{DD}/2$ – 1.298	$V_{DD}/2$ – 1.228	V
	RefPower = medium Opamp bias = low	V_{REFHI}	Ref High	$V_{DD}/2$ + Bandgap	$V_{DD}/2$ + 1.219	$V_{DD}/2$ + 1.293	$V_{DD}/2$ + 1.353	V
		V_{AGND}	AGND	$V_{DD}/2$	$V_{DD}/2$ – 0.037	$V_{DD}/2$ – 0.001	$V_{DD}/2$ + 0.036	V
		V_{REFLO}	Ref Low	$V_{DD}/2$ – Bandgap	$V_{DD}/2$ – 1.359	$V_{DD}/2$ – 1.299	$V_{DD}/2$ – 1.229	V

Table 20. 3.3-V DC Analog Reference Specifications *(continued)*

Reference ARF_CR [5:3]	Reference Power Settings	Symbol	Reference	Description	Min	Typ	Max	Units
0b110	RefPower = high Opamp bias = high	V_{REFHI}	Ref High	2 × Bandgap	2.510	2.595	2.655	V
		V_{AGND}	AGND	Bandgap	1.276	1.301	1.332	V
		V_{REFLO}	Ref Low	V_{SS}	V_{SS}	V_{SS} + 0.006	V_{SS} + 0.031	V
	RefPower = high Opamp bias = low	V_{REFHI}	Ref High	2 × Bandgap	2.513	2.594	2.656	V
		V_{AGND}	AGND	Bandgap	1.275	1.301	1.331	V
		V_{REFLO}	Ref Low	V_{SS}	V_{SS}	V_{SS} + 0.004	V_{SS} + 0.021	V
	RefPower = medium Opamp bias = high	V_{REFHI}	Ref High	2 × Bandgap	2.516	2.595	2.657	V
		V_{AGND}	AGND	Bandgap	1.275	1.301	1.331	V
		V_{REFLO}	Ref Low	V_{SS}	V_{SS}	V_{SS} + 0.003	V_{SS} + 0.017	V
	RefPower = medium Opamp bias = low	V_{REFHI}	Ref High	2 × Bandgap	2.520	2.595	2.658	V
		V_{AGND}	AGND	Bandgap	1.275	1.300	1.331	V
		V_{REFLO}	Ref Low	V_{SS}	V_{SS}	V_{SS} + 0.002	V_{SS} + 0.015	V
0b111	All power settings. Not allowed for 3.3 V.	–	–	–	–	–	–	–

11.3.8 DC Analog PSoC Block Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters are measured at 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 21. DC Analog PSoC Block Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
R_{CT}	Resistor unit value (continuous time)	–	12.2	–	kΩ	
C_{SC}	Capacitor unit value (switched capacitor)	–	80	–	fF	

11.3.9 DC POR and LVD Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters are measured at 5 V or 3.3 V at 25 °C and are for design guidance only.

Table 25. AC Chip Level Specifications *(continued)*

Symbol	Description	Min	Typ	Max	Units	Notes
$t_{POWERUP}$	Time from end of POR to CPU executing code	–	16	100	ms	Power-up from 0 V. See the System Resets section of the PSoC Technical Reference Manual.
t_{jit_IMO}[32]	24 MHz IMO cycle-to-cycle jitter (RMS)	–	200	1200	ps	
	24 MHz IMO long term N cycle-to-cycle jitter (RMS)	–	900	6000	ps	N=32
	24 MHz IMO period jitter (RMS)	–	200	900	ps	

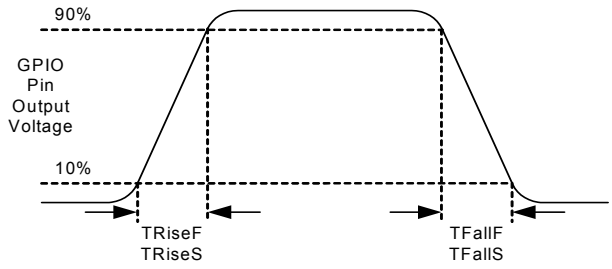
11.4.2 AC GPIO Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters are measured at 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 26. AC GPIO Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
F_{GPIO}	GPIO operating frequency	0	–	12	MHz	Normal strong mode
t_{RiseF}	Rise time, normal strong mode, Cload = 50 pF	3	–	18	ns	V_{DD} = 4.5 to 5.25 V, 10% to 90%
t_{FallF}	Fall time, normal strong mode, Cload = 50 pF	2	–	18	ns	V_{DD} = 4.5 to 5.25 V, 10% to 90%
t_{RiseS}	Rise time, slow strong mode, Cload = 50 pF	10	27	–	ns	V_{DD} = 3 to 5.25 V, 10% to 90%
t_{FallS}	Fall time, slow strong mode, Cload = 50 pF	10	22	–	ns	V_{DD} = 3 to 5.25 V, 10% to 90%

Figure 12. GPIO Timing Diagram



Notes
29. 4.75 V < V_{DD} < 5.25 V.
30. 3.0 V < V_{DD} < 3.6 V. See application note Adjusting PSoC® Trims for 3.3 V and 2.7 V Operation – AN2012 for information on trimming for operation at 3.3 V.
31. See the individual user module datasheets for information on maximum frequencies for user modules.
32. Refer to Cypress Jitter Specifications application note, Understanding Datasheet Jitter Specifications for Cypress Timing Products – AN5054 for more information.

11.4.3 AC Full Speed USB Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –10 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –10 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters are measured at 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 27. AC Full Speed (12 Mbps) USB Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
t_{RFS}	Transition rise time	4	–	20	ns	For 50 pF load
t_{FSS}	Transition fall time	4	–	20	ns	For 50 pF load
t_{RFMFS}	Rise/fall time matching: (t_R/t_F)	90	–	111	%	For 50 pF load
$t_{DRATEFS}$	Full speed data rate	12 – 0.25%	12	12 + 0.25%	Mbps	

11.4.9 AC Programming Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters are measured at to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 35. AC Programming Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
t_{RSCLK}	Rise time of SCLK	1	–	20	ns	
t_{FSCLK}	Fall time of SCLK	1	–	20	ns	
t_{SSCLK}	Data setup time to falling edge of SCLK	40	–	–	ns	
t_{HSCLK}	Data hold time from falling edge of SCLK	40	–	–	ns	
F_{SCLK}	Frequency of SCLK	0	–	8	MHz	
t_{ERASEB}	Flash erase time (block)	–	10	–	ms	
t_{WRITE}	Flash block write time	–	40	–	ms	
t_{DSCLK}	Data out delay from falling edge of SCLK	–	–	45	ns	V_{DD} > 3.6
t_{DSCLK3}	Data out delay from falling edge of SCLK	–	–	50	ns	3.0 ≤ V_{DD} ≤ 3.6
$t_{ERASEALL}$	Flash erase time (bulk)	–	40	–	ms	Erase all blocks and protection fields at once
$t_{PROGRAM\_HOT}$	Flash block erase + flash block write time	–	–	100[34]	ms	0 °C ≤ Tj ≤ 100 °C
$t_{PROGRAM\_COLD}$	Flash block erase + flash block write time	–	–	200[34]	ms	–40 °C ≤ Tj ≤ 0 °C

Note

34. For the full industrial range, the user must employ a temperature sensor user module (FlashTemp) and feed the result to the temperature argument before writing. See the Flash APIs application note Design Aids – Reading and Writing PSoC® Flash – AN2015 for more information.

- Getting Started guide
- USB 2.0 cable

12.4.2 CY3207ISSP In-System Serial Programmer (ISSP)

The CY3207ISSP is a production programmer. It includes protection circuitry and an industrial case that is more robust than the MiniProg in a production-programming environment.

Note: CY3207ISSP needs special software and is not compatible with PSoC Programmer. The kit includes:

- CY3207 programmer unit
- PSoC ISSP software CD
- 110 ~ 240 V power supply, Euro-Plug adapter
- USB 2.0 cable

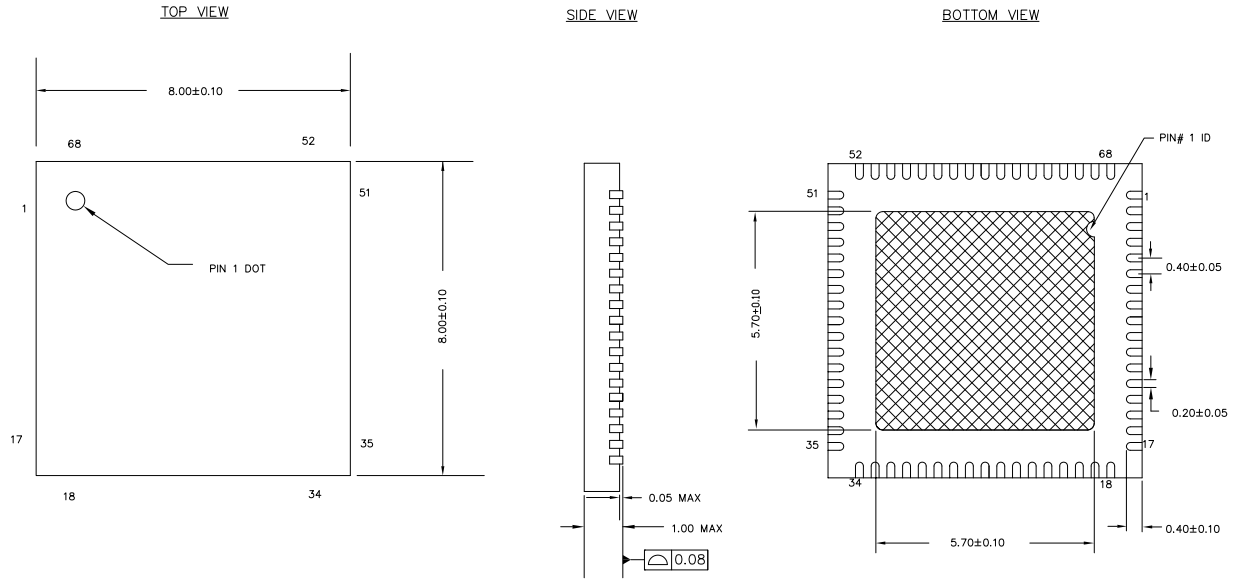
12.5 Accessories (Emulation and Programming)

Table 39. Emulation and Programming Accessories

Part #	Pin Package	Flex-Pod Kit[38]	Foot Kit[39]	Adapter[40]
CY8C24794-24LQXI	56-pin QFN	CY3250-24X94QFN	None	Adapters can be found at http://www.emulation.com.

Notes
38. Flex-Pod kit includes a practice flex-pod and a practice PCB, in addition to two flex-pods.
39. Foot kit includes surface mount feet that are soldered to the target PCB.
40. Programming adapter converts non-DIP package to DIP footprint. Specific details and ordering information for each of the adapters are found at http://www.emulation.com.

Figure 19. 68-pin QFN (8 × 8 × 1.0 mm) LT68 5.7 × 5.7 E-Pad (Sawn Type) Package Outline, 001-09618



NOTES:

1. HATCH AREA IS SOLDERABLE EXPOSED METAL.
2. REFERENCE JEDEC#: MO−220
3. PACKAGE WEIGHT: 17 ± 2mg
4. ALL DIMENSIONS ARE IN MILLIMETERS

001-09618 *E

16. Document Conventions

16.1 Units of Measure

Symbol	Unit of Measure	Symbol	Unit of Measure
°C	degree Celsius	mV	millivolt
dB	decibels	nA	nanoampere
fF	femtofarad	ns	nanosecond
kHz	kilohertz	nV	nanovolt
kΩ	kilohms	Ω	ohms
MHz	megahertz	pA	picoampere
µA	microampere	pF	picofarad
µs	microsecond	ps	picosecond
µV	microvolt	%	percent
mA	milliampere	rt-Hz	root hertz
mm	millimeter	V	volt
ms	millisecond	W	watt

16.2 Numeric Conventions

Hexadecimal numbers are represented with all letters in uppercase with an appended lowercase ‘h’ (for example, ‘14h’ or ‘3Ah’). Hexadecimal numbers may also be represented by a ‘0x’ prefix, the C coding convention. Binary numbers have an appended lowercase ‘b’ (for example, ‘01010100b’ or ‘01000011b’). Numbers not indicated by an ‘h’ or ‘b’ are decimal.

17. Glossary

active high	6. A logic signal having its asserted state as the logic 1 state. 7. A logic signal having the logic 1 state as the higher voltage of the two states.
analog blocks	The basic programmable opamp circuits. These are SC (switched capacitor) and CT (continuous time) blocks. These blocks can be interconnected to provide ADCs, DACs, multi-pole filters, gain stages, and much more.
analog-to-digital (ADC)	A device that changes an analog signal to a digital signal of corresponding magnitude. Typically, an ADC converts a voltage to a digital number. The digital-to-analog (DAC) converter performs the reverse operation.
API (Application Programming Interface)	A series of software routines that comprise an interface between a computer application and lower level services and functions (for example, user modules and libraries). APIs serve as building blocks for programmers that create software applications.
asynchronous	A signal whose data is acknowledged or acted upon immediately, irrespective of any clock signal.
Bandgap reference	A stable voltage reference design that matches the positive temperature coefficient of VT with the negative temperature coefficient of VBE, to produce a zero temperature coefficient (ideally) reference.
bandwidth	1. The frequency range of a message or information processing system measured in hertz. 2. The width of the spectral region over which an amplifier (or absorber) has substantial gain (or loss); it is sometimes represented more specifically as, for example, full width at half maximum.
bias	1. A systematic deviation of a value from a reference value. 2. The amount by which the average of a set of values departs from a reference value. 3. The electrical, mechanical, magnetic, or other force (field) applied to a device to establish a reference level to operate the device.

17. Glossary *(continued)*

external reset (XRES)	An active high signal that is driven into the PSoC device. It causes all operation of the CPU and blocks to stop and return to a pre-defined state.
flash	An electrically programmable and erasable, non-volatile technology that provides users with the programmability and data storage of EPROMs, plus in-system erasability. Non-volatile means that the data is retained when power is off.
Flash block	The smallest amount of Flash ROM space that may be programmed at one time and the smallest amount of Flash space that may be protected. A Flash block holds 64 bytes.
frequency	The number of cycles or events per unit of time, for a periodic function.
gain	The ratio of output current, voltage, or power to input current, voltage, or power, respectively. Gain is usually expressed in dB.
I^2C	A two-wire serial computer bus by Philips Semiconductors (now NXP Semiconductors). I2C is an Inter-Integrated Circuit. It is used to connect low-speed peripherals in an embedded system. The original system was created in the early 1980s as a battery control interface, but it was later used as a simple internal bus system for building control electronics. I2C uses only two bi-directional pins, clock and data, both running at +5V and pulled high with resistors. The bus operates at 100 kbits/second in standard mode and 400 kbits/second in fast mode.
ICE	The in-circuit emulator that allows users to test the project in a hardware environment, while viewing the debugging device activity in a software environment (PSoC Designer).
input/output (I/O)	A device that introduces data into or extracts data from a system.
interrupt	A suspension of a process, such as the execution of a computer program, caused by an event external to that process, and performed in such a way that the process can be resumed.
interrupt service routine (ISR)	A block of code that normal code execution is diverted to when the M8C receives a hardware interrupt. Many interrupt sources may each exist with its own priority and individual ISR code block. Each ISR code block ends with the RETI instruction, returning the device to the point in the program where it left normal program execution.
jitter	1. A misplacement of the timing of a transition from its ideal position. A typical form of corruption that occurs on serial data streams. 2. The abrupt and unwanted variations of one or more signal characteristics, such as the interval between successive pulses, the amplitude of successive cycles, or the frequency or phase of successive cycles.
low-voltage detect (LVD)	A circuit that senses V_{DD} and provides an interrupt to the system when V_{DD} falls lower than a selected threshold.
M8C	An 8-bit Harvard-architecture microprocessor. The microprocessor coordinates all activity inside a PSoC by interfacing to the Flash, SRAM, and register space.
master device	A device that controls the timing for data exchanges between two devices. Or when devices are cascaded in width, the master device is the one that controls the timing for data exchanges between the cascaded devices and an external interface. The controlled device is called the ***slave device.***
microcontroller	An integrated circuit chip that is designed primarily for control systems and products. In addition to a CPU, a microcontroller typically includes memory, timing circuits, and IO circuitry. The reason for this is to permit the realization of a controller with a minimal quantity of chips, thus achieving maximal possible miniaturization. This in turn, reduces the volume and the cost of the controller. The microcontroller is normally not used for general-purpose computation as is a microprocessor.
mixed-signal	The reference to a circuit containing both analog and digital techniques and components.

3. PMA Index Register fails to auto-increment with CPU_Clock set to SysClk/1 (24 MHz).

■ PROBLEM DEFINITION

When the device is operating at 4.75 to 5.25 V and the CPU_Clock is set to SysClk/1 (24 MHz), the USB PMA Index Register may fail to increment automatically when used in an OUT endpoint configuration at Full-Speed. When the application program attempts to use the bReadOutEP() function the first byte in the PMA buffer is always returned.

■ TRIGGER CONDITION(S)

An internal flip-flop hold problem associated with Index Register increment function. All reads of the associated RAM originate from the first byte. The hold problem has no impact on other circuits or functions within the device.

■ WORKAROUND

To make certain that the index register properly increments, set the CPU_Clock to SysClk/2 (12 MHz) during the read of the PMA buffer. An example for the clock adjustment method is listed below.

PSoC Designer™ 4.3 User Module workaround: PSoC Designer Release 4.3 and subsequent releases includes a revised full-speed USB User Module with the revised firmware work-around included (see example below).

```
;;
;; 24 MHz read PMA workaround
;;
M8C_SetBank1
mov A, reg[OSC_CR0]
push A
and A, 0xf8 ;clear the clock bits (briefly chg the cpu_clk to 3 MHz)
or A, 0x02 ;will set clk to 12Mhz

mov reg[OSC_CR0],A ;clk is now set at 12 MHz
M8C_SetBank0
.loop:
   mov A, reg[PMA0_DR] ; Get the data from the PMA space
   mov [X], A ; save it in data array
   inc X ; increment the pointer
   dec [USB_APITemp+1] ; decrement the counter
   jnz .loop ; wait for count to zero out
;;
;; 24MHz read PMA workaround (back to previous clock speed)
;;
pop A ;recover previous reg[OSC_CR0] value
M8C_SetBank1
mov reg[OSC_CR0],A ;clk is now set at previous value
M8C_SetBank0
;;
;;   end 24Mhz read PMA workaround
```

19. Document History Page

Document Title: CY8C24094/CY8C24794/CY8C24894/CY8C24994, PSoC® Programmable System-on-Chip™ Document Number: 38-12018				
Revision	**ECN**	**Orig. of Change**	**Submission Date**	**Description of Change**
**	133189	NWJ	01/27/2004	New silicon and new document – Advance datasheet.
*A	251672	SFV	See ECN	First Preliminary datasheet. Changed title to encompass only the CY8C24794 because the CY8C24494 and CY8C24694 are not being offered by Cypress.
*B	289742	HMT	See ECN	Add standard DS items from SFV memo. Add Analog Input Mux on pinouts. 2 MACs. Change 512 bytes of SRAM to 1 K. Add dimension key to package. Remove HAPI. Update diagrams, registers and specs.
*C	335236	HMT	See ECN	Add CY logo. Update CY copyright. Update new CY.com URLs. Re-add ISSP programming pinout notation. Add Reflow Temp. table. Update features (MAC, Oscillator, and voltage range), registers (INT_CLR2/MSK2, second MAC), and specs. (Rext, IMO, analog output buffer...).
*D	344318	HMT	See ECN	Add new color and logo. Expand analog arch. diagram. Fix I/O #. Update Electrical Specifications.
*E	346774	HMT	See ECN	Add USB temperature specifications. Make datasheet Final.
*F	349566	HMT	See ECN	Remove USB logo. Add URL to preferred dimensions for mounting MLF packages.
*G	393164	HMT	See ECN	Add new device, CY8C24894 56-pin MLF with XRES pin. Add Fimousb3v char. to specs. Upgrade to CY Perform logo and update corporate address and copyright.
*H	469243	HMT	See ECN	Add ISSP note to pinout tables. Update typical and recommended Storage Temperature per industrial specs. Update Low Output Level maximum I/OL budget. Add FLS_PR1 to Register Map Bank 1 for users to specify which Flash bank should be used for SROM operations. Add two new devices for a 68-pin QFN and 100-ball VFBGA under RPNs: CY8C24094 and CY8C24994. Add two packages for 68-pin QFN. Add OCD non-production pinouts and package diagrams. Update CY branding and QFN convention. Add new Dev. Tool section. Update copyright and trademarks.
*I	561158	HMT	See ECN	Add Low Power Comparator (LPC) AC/DC electrical spec. tables. Add CY8C20x34 to PSoC Device Characteristics table. Add detailed dimensions to 56-pin QFN package diagram and update revision. Secure one package diagram/manufacturing per QFN. Update emulation pod/feet kit part numbers. Fix pinout type-o per TestTrack.
*J	728238	HMT	See ECN	Add CapSense SNR requirement reference. Update figure standards. Update Technical Training paragraphs. Add QFN package clarifications and dimensions. Update ECN-ed Amkor dimensioned QFN package diagram revisions. Reword SNR reference. Add new 56-pin QFN spec.
*K	2552459	AZIE / PYRS	08/14/08	Add footnote on AGND descriptions to avoid using P2[4] for digital signaling as it may add noise to AGND. Remove reference to CMP_GO_EN1 in Map Bank 1 Table on Address 65; this register has no functionality on 24xxx. Add footnote on die sales. Add description 'Optional External Clock Input' on P1[4] to match description of P1[4].
*L	2616550	OGNE / PYRS	12/05/08	Updated Programmable Pin Configuration detail. Changed title from PSoC® Mixed-Signal Array to PSoC® Programmable System-on-Chip™
*M	2657956	DPT / PYRS	02/11/09	Added package diagram 001-09618 and updated Ordering Information table

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